# RT3P11M

Composite Transistor With Resistor For Switching Application Silicon Epitaxial Type

# DESCRIPTION

RT3P11M is composite transistor built with two RT1P141 chips in SC-88 package.

# FEATURE

Built-in bias resistor (R1=10k $\Omega$ , R2=10k $\Omega$ ) Mini package for easy mounting

# APPLICATION

Inverted circuit, Switching circuit, Interface circuit, Driver circuit



# MAXIMUM RATING(Ta=25°C)(RTr1, RTr2 COMMON)

SYMBOL	PARAMETER	RATING	UNIT	
VCBO	Collector to Base voltage	-50	V	
VEBO	Emitter to Base voltage	-10	V	
VCEO	Collector to Emitter voltage	-50	V	
$V_{\rm IN}$	Input voltage	-40	V	
Ic	Collector current	-100	mA	
ICM	Peak Collector current	-200	mA	
Рт	Total dissipation	200	mW	
Tj	Junction temperature	+150	°C	
$T_{stg}$	Storage temperature	-55~+150	°C	



## ELECTRICAL CHARACTERISTICS(Ta=25°C)(RTr1, RTr2 COMMON)

SYMBOL	PARAMETER	TEST CONDITIONS	LIMITS			UNIT
			MIN	TYP	MAX	UNII
V(BR)CEO	Collector to Emitter breakdown voltage	$I_C$ =-100 $\mu$ A, $R_{BE}$ = $\infty$	-50	—	—	V
Ісво	Collector cut off current	$V_{CB}$ =-50V, $I_E$ =0	—	—	-0.1	μA
IEBO	Emitter cut off current	V <sub>EB</sub> =-5V, I <sub>C</sub> =0	-192	-250	-357	μA
hFE	DC forward current gain	V <sub>CE</sub> =-5V, I <sub>C</sub> =-10mA	50	—	—	-
VCE(sat)	Collector to Emitter saturation voltage	I <sub>c</sub> =-10mA, I <sub>B</sub> =-0.5mA	—	-0.1	-0.3	V
V <sub>I(ON)</sub>	Input on voltage	V <sub>CE</sub> =-0.2V, I <sub>C</sub> =-5mA	—	-1.5	-3.0	V
V <sub>I(OFF)</sub>	Input off voltage	$V_{CE}$ =-5V, I <sub>C</sub> =-100 $\mu$ A	-0.8	-1.1	—	V
$R_1$	Input resistor	-	7.0	10	13	kΩ
$R_2/R_1$	Resistor ratio	-	0.9	1.0	1.1	_
fT	Gain band width product	V <sub>CE</sub> =-6V, I <sub>E</sub> =10mA	—	150	—	MHz

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Ta=-40°C

-100

-2.0

-1.5

-1.0

Ta=25°C

-10

### (RTr1,RTr2 COMMON) TOTAL DISSIPATION DC FORWARD CURRENT GAIN VS AMBIENT TEMPERATURE VS COLLECTOR CURRENT 300 1000 VCE=-5V (MM) DC FORWARD CURRENT GAIN HFE TOTAL DISSIPATION PT 00 100 10 Ta=85℃ 0 1 0 25 50 75 100 125 150 -0.1 -1 AMBIENT TEMPERATURE Ta (°C) COLLECTOR CURRENT IC(mA) INPUT ON VOLTAGE COLLECTOR CURRENT VS COLLECTOR CURRENT VS INPUT OFF VOLTAGE -10 -1000 VCE=-0.2V VCE=-5V COLLECTOR CURRENT IC ( $\mu$ A) INPUT ON VOLTAGE VI(on) (V) Ta=-40°C Ta=85°C -100 -1 Ta=25°C Ta=85°C Ta=25°C -10 °C 40 -0.1 -1 -0.1 -1 -10 -100 -0.5 -0.0 COLLECTOR CURRENT IC(mA) INPUT OFF VOLTAGE VI(off) (V) COLLECTOR TO EMITTER SATURATION VOLTAGE VS COLLECTOR CURRENT COLLECTOR TO EMITTER SATURATION VOLTAGE -1 IC/IB=20/1 Ta=85°C Ta=25°C VCE(sat) (V) Ta=-40°C -0.1 -0.01

### TYPICAL CHARACTERISTICS

-1

-10

COLLECTOR CURRENT IC(mA)

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-100

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